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Docket No.: M4065.0019/P019-A  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Leonard Forbes, et al.

Examiner: Kiesha L. Rose

Application No.: 09/750,111

Art Unit: 2822

Filed: December 29, 2000

For: HIGH DENSITY SRAM CELL WITH  
LATCHED VERTICAL TRANSISTORS

**REQUEST FOR RECONSIDERATION**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

This paper is in response to the Office Action dated May 11, 2004. Please reconsider the above-identified U.S. patent application in light of the following remarks:

**Status of the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks** begin on page 8 of this paper.